

Reliable Electronics? Precise Current Measurements May Tell You Otherwise...

Hans Manhaeve Ridgetop Europe

Overview

- Reliable Electronics
- Precise current measurements?
 - Accurate Accuracy
 - Resolution
 - Repeatability
 - Understanding specifications
- Precise current measurements & reliability
 - Detecting failures
 - Burn-in replacement
- Cases
- Conclusions

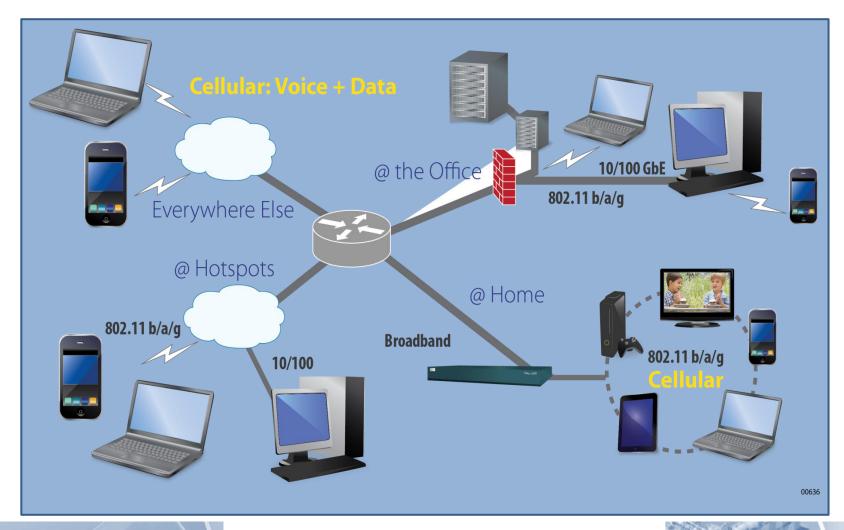


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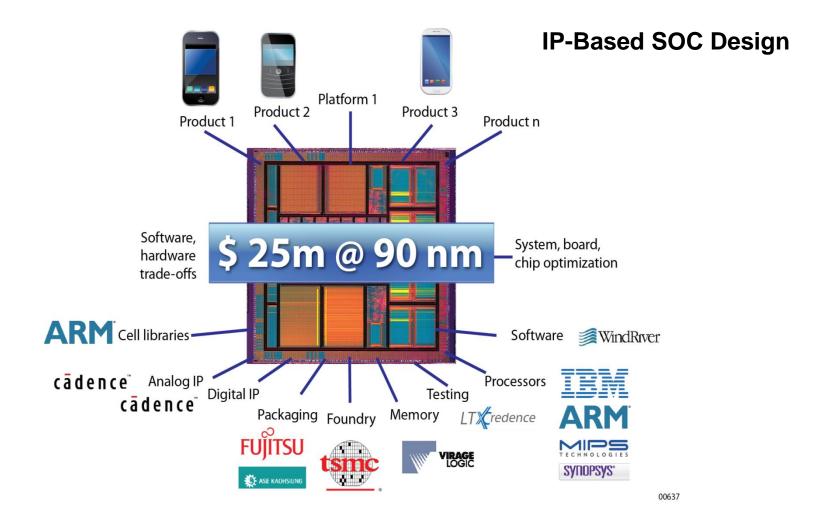
The Need for Test & Reliable Operation



Any Device, Any Time, Anywhere



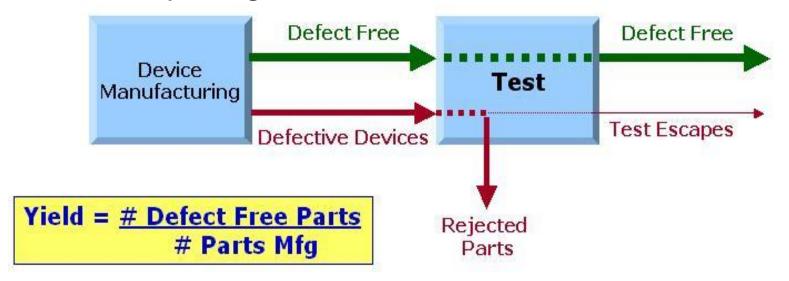
The Need for Test & Reliable Operation



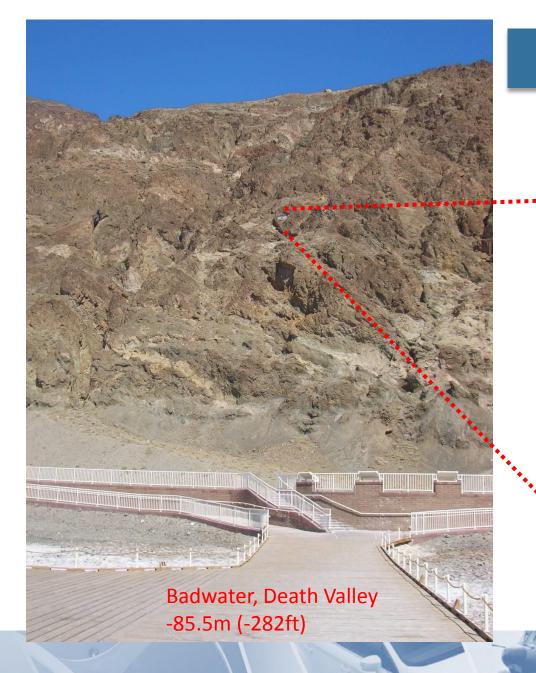


The Need for Test

 But we still need to test every single transistor and every single unit



 Test is an important factor of product manufacturing costs (15 → 50 →%)



"Find the Defect"



Ridgetop

"Find the Defect"



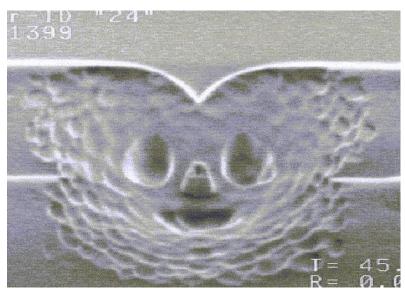
Hyatt Regency - Maui

Finding Defects

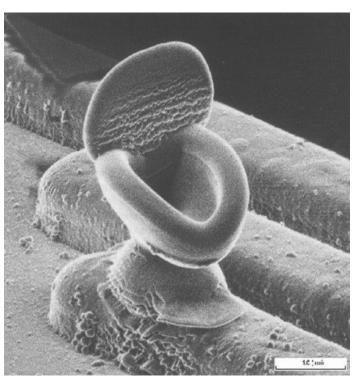
- Requires to be at the right place and look in the right direction at the right time
 - Apply the proper test conditions
- Have a good set of binoculars
 - Have the right test instrument available
- And know how to use your binoculars and keep them steady
 - Know how to use your instruments
 - Ensure reliable and repeatable test results



The Need for Test



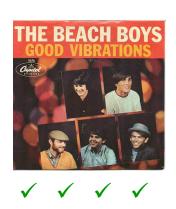
Madge, ITC04

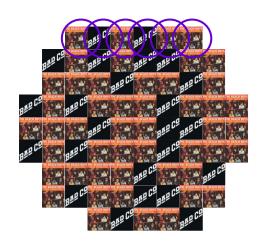


Butler, ITC07

Yield has a simple definition

$$Yield = \frac{good\ chips}{total\ chips}$$







Challenge is in separating "good" from "bad"

Yield and Reliability - Ambiguity

 $Measured\ Yield = \frac{good\ parts + test\ escapes - type\ I\ failures}{all\ parts}$





GEORGE THOROGOOD

BAD TO THE BONE

- Competing definitions of "good"
 - Ideal: works in customer's application
 - → Can't measure this until it's too late!
 - Is high leakage from a defect or fast transistors?
 - Most chips work at 0.7V, this one doesn't??
 - How complete are these tests?
- Need to agree on "passes the tests we apply"
- Result: Test & yield are part of the same discussion!

- Historically, testing was functional
 - Does the device do what it is supposed to?
 - Function primarily defined logically
 - Yield relates to function
- Next, structural tests were developed
 - Is every circuit structure (e.g., gate) present and working?
 - Coverage metrics are logical (stuck-at fault coverage)
 - Yield relates to structure
- Defect-oriented testing starts with defects
 - What could go wrong with this device?
 - If it went wrong, what would change about the device?
 - Any measurable behavior could be affected, not just function
 - → timing, current, voltage, temperature dependence
 - Yield relates to absence of defects



- Semiconductor evolution enables further integration
 - Transistors are nearly for free
- New processes are used for mass production long before they are mature
 - Systematic and random defects
 - Reliability concerns
- Increasing device complexity
 - The "embedded" world
 - Analog Digital Memory Software



- Market demands for cheaper and better electronics
- Market demands for RELIABLE electronics



Lifetime reliability becomes a serious concern



Failure mechanisms

EM / SM NBTI / PBTI

QBD / TDDB

HCI

Reliability-related factors

Temperature

Voltage / Current

Frequency

Radiation

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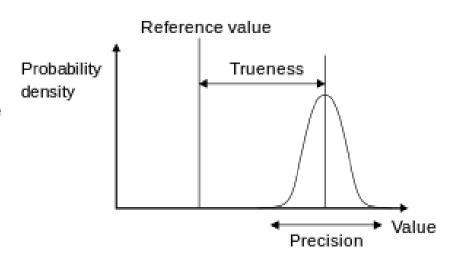
Qualifying Measurement Results

- Quality and reliability decisions require data
- Gathering data == Making measurements
- Measurements are qualified in terms of
 - Accuracy
 - Resolution
 - Precision Repeatability



Accurate - Accuracy

- Accurate
 - Correct, exact, error-free, on target, ...
- Accuracy
 - Measurement ← → actual (true) value
 - ISO 5725-1:
 - → Accuracy consists of
 - Trueness (proximity of measurement results to the true value)
 - Precision (repeatability or reproducibility of the measurement)



Source: Wikipedia



Resolution

Resolution

- smallest change in the underlying physical quantity that produces a response in the measurement
- Linked to noise levels or # of bits

Effective resolution

- # of bits ←→ ENOB
- S/N ratio of signal path
- Sampling frequency
- Sampling technique used

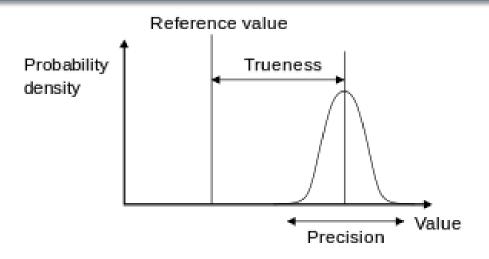


Repeatability

- Precision / Repeatability
 - variation in measurements taken by a single person or instrument on the same item and under the same conditions
 - Deviation of measured values
- Reproducibility
 - degree to which repeated measurements under unchanged conditions show the same results
- Also function of signal stability / settling



The Test Perspective



Trueness

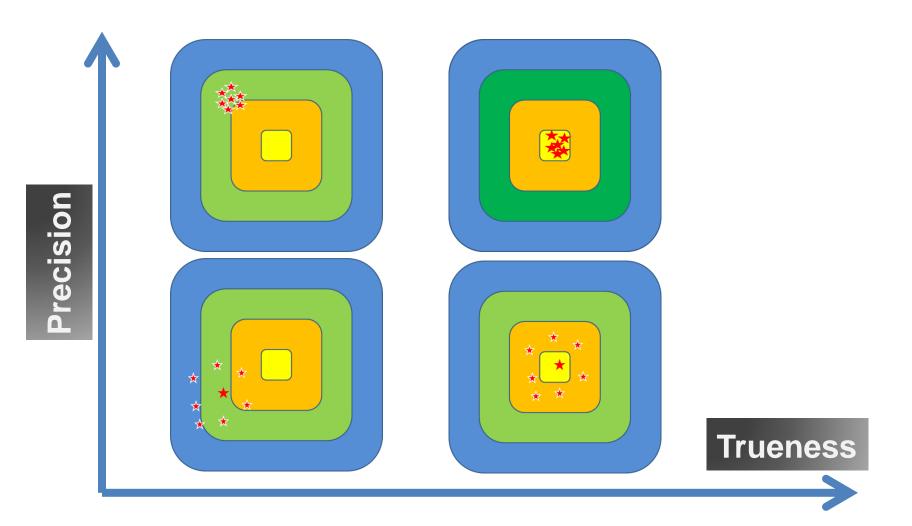
- Relates to systematic errors
- Subject to calibration
- Not so critical what matters is that "all are treated equal"

Precision

- Relates to random errors
- Reflects instrument quality and performance
- Is key to decision making



Trueness versus precision

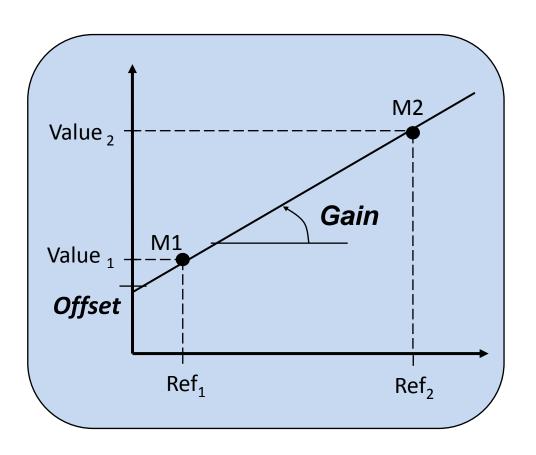




Calibration Considerations

Offset & gain

- Offset
 - → Precision is key
- Gain
 - → Set-point reproducibility and precision are key





- Example: Teradyne Catalyst
 - matrix source specifications

Range	Resolution	Accuracy	Average Error		
200mA	25 uA	+/-(0.1% + 100 uA)	+/-	225	uA
100mA	12.5 uA	+/-(0.1% + 50 uA)	+/-	112.5	uA
50mA	6.25 uA	+/-(0.1% + 25 uA)	+/-	56.25	uA
20mA	2.5 uA	+/-(0.1% + 10 uA)	+/-	22.5	uA
10mA	1.25 uA	+/-(0.1% + 5 uA)	+/-	11.25	uA
- 5m A	625 n A	1/(0.4% + 2.5 11/1)	. /	E 625	11Λ
2mA	250 nA	+/-(0.1% + 1 uA)	+/-	2.25	uA
1mA	125 NA	+/-(U.1% + 6UU NA + 1 NA/V)	+/-	1.225	UA
500uA	62.5 nA	+/-(0.1% + 350 nA + 1 nA/V)	+/-	663	nA
200uA	25 nA	+/-(0.1% + 200 nA + 1 nA/V)	+/-	325	nA
100uA	12.5 nA	+/-(0.1% + 150 nA + 1 nA/V)	+/-	213	nA
50uA	6.25 nA	+/-(0.1% + 125 nA + 1 nA/V)	+/-	156	nA
20uA	2.5 nA	+/-(0.1% + 110 nA + 1 nA/V)	+/-	123	nA
10uA	1.25 nA	+/-(0.1% + 105 nA + 1 nA/V)	+/-	116	nA
5uA	625 pA	+/-(0.1% + 103 nA + 1 nA/V)	+/-	113	nA



- Example: Teradyne Catalyst matrix source
 - 2mA range, 14 bit
 - Nominal resolution: 250nA
 - Accuracy: ± (0.1% measure + 1uA)
 - Measurement error:

min: $\pm 1.25 \mu A$ -- max: $\pm 3.25 \mu A$

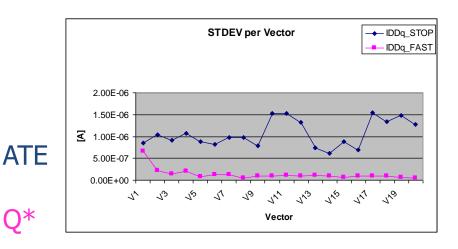
- True Value: 1.5mA
 - \rightarrow Measured value: 1.49725 1.50275mA (0.37%)
- True Value: 100µA
 - → Measured value: $98.65 101.35\mu A$ (2.7%)

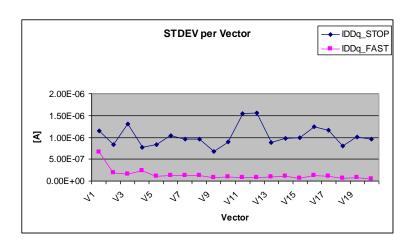


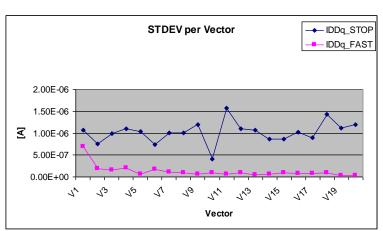
Q-Star QD-1011 specs:

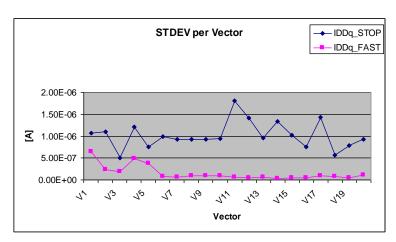
$\Delta I_{DDQ RMS} = f(C_L, \#Samples) [nA]^{(5)}$							
Measurement Range (1)	C _L			# Samples ⁽²⁾			
weasurement Range	$0.0 - 0.5 \ \mu F^{(3)}$	$0.5 - 2.0 \ \mu F^{(3)}$	1.0 – 10.0 μF ⁽⁴⁾	# Samples			
	20	50	330	1			
0 – 100 μΑ	15	25	230	4			
	10	15	110	16			
	50	90	500	1			
0 – 1 mA	30	60	300	4			
	15	20	150	16			
	360	400	550	1			
0 – 10 mA	200	220	290	4			
	125	130	180	16			
	2200	2200	2200	1			
0 – 30 mA	700	700	700	4			
	220	220	220	16			







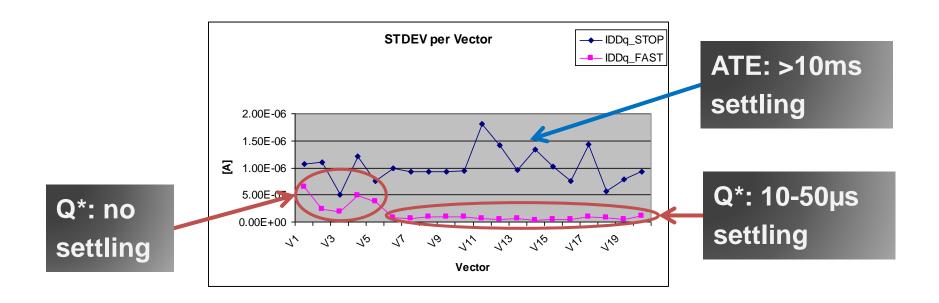




IDDQ Measurement repeatability, 20 strobes, 10 iterations per strobe



Impact of Settling



- ATE measurements: ~100ms/measurement
- Q* measurements: 150-200µs/measurement

Overview

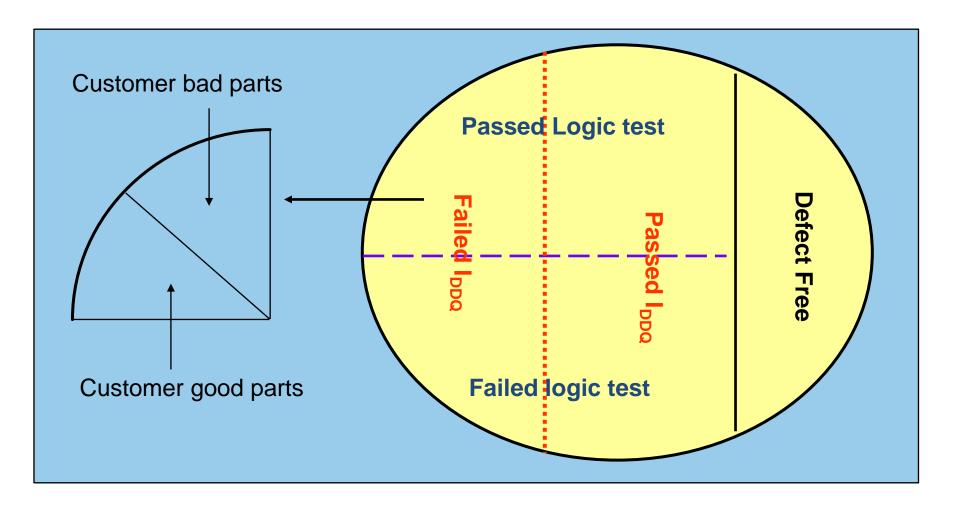
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Current & Reliability

- Deviations in current behavior
 - indication for reliability risks of devices and systems.
 - Often overlooked as focus is typically on functional behavior
- Research results published by IBM and Sematech clearly shows that "IDDQ-only" failures are posing reliability risks.
- High correlation between burn-in failures and IDDQ test failures.
- Appropriate current measurements can easily reveal problem parts/systems
 - Information is "hidden" in both static as well as dynamic current behavior

Test Qualification





Test Coverage

- What coverage do we need?
 - 4 out of 10 lodg only failures pose problems
 - Desired: 100 (10) (1) ppm reliability level
 - → Acceptable defect level : 250 (25) (2.5) ppm
 - → Case 1 : "IDDQ yield loss" : 5% (50000ppm)
 - Required IDDQ coverage : 99.5% (99.95%) (99.995%)
 - → Case 2: "IDDQ yield loss": 0.1% (1000ppm)
 - Required IDDQ coverage: 75% (97.5%) (99.75%)



The Value of Eliminating Burn-In

- INTEL: 1.25 M\$ savings
 - product : i960JX CPU
 - elimination of Burn-in

- SEMATECH Consortium
 - monthly production of 1 M IC's
 - savings ranging from 267 k\$ to 1.95 M\$ (monthly!)
 - →Burn-in replaced by I_{DDQ} + voltage stress



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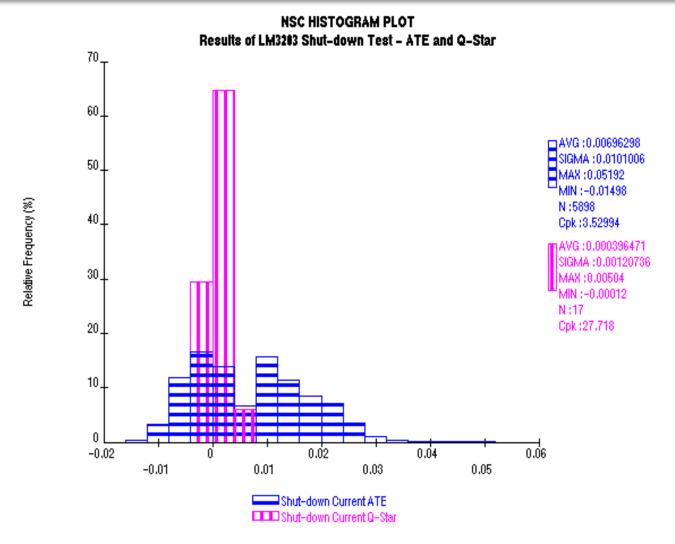
Case 1

Case 1:

- Qualification of a LM3203 voltage regulator
- Data Source: National Semiconductor
- Test Subject: Shutdown current
- Test Focus: Instrument precision



Case 1



3/23/2006 10:48:59 AM Mbayse data.../lm3203qstar.csv

Considerations

- Q-Star QD-1011 based measurements show a tighter distribution and a higher measurement repeatability.
 - → Measurement repeatability of 1-2nA for a 100µA module was obtained (0.002% of range)
- The improved measurement quality enabled easy detection of outlier devices that escape the ATE current based tests that are marginal to comprehensive time expensive specification tests and lead to field failures.
- Additional experiments confirmed the correctness of the QD-1011 results



Conclusions

- An IDDx based test strategy using Q-Star add-on current measurement instrumentation has proven to provide improved measurement quality combined with test cost reduction.
- Reduction of Field failure rates and Field returns
- Further benefits include test time reduction, measurable improvement in test quality and test confidence.
- The approach provides a common test solution that can be applied across device technologies and product mixes and has been successfully adopted as a working flow in the production test environment.



Case 2

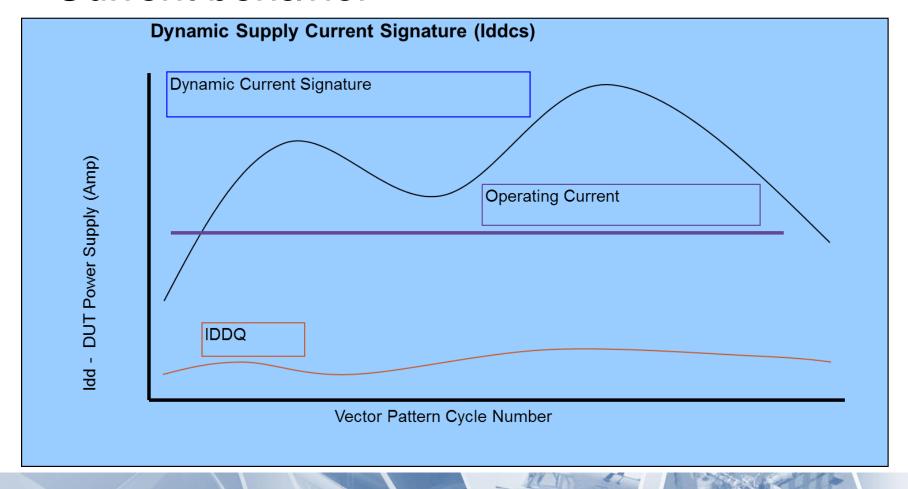
- Reliability issue with high performance network device
- Data Source: LSI Logic
- Test Subject: Power Profiling
- Test Focus: Instrument precision



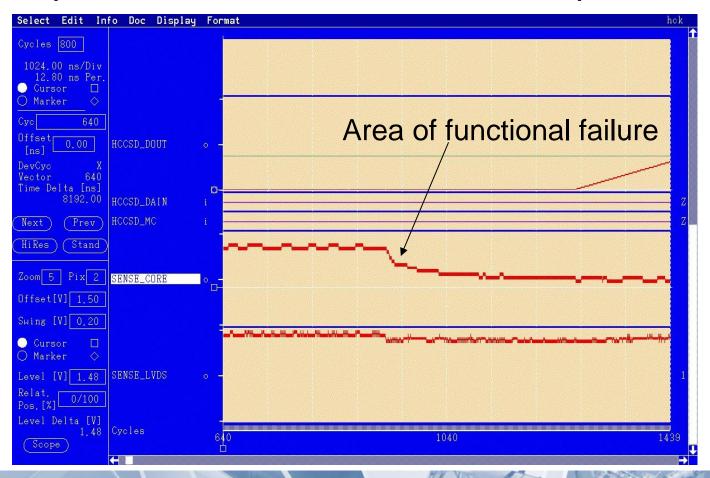
- Field return issue
 - Limitation of test platform measurement capabilities was masking devices with potential reliability risk
 - Detailed FA on field returns revealed
 - → Sensitivity to Memory-BIST failures @ Low Vdd
 - → VDD droop on internal supply test pin under particular conditions
- IC Design/Application Engineers wanted better Power Management
 - Device power profile and marketing requirements
 - Feedback to design tools for software tool calibration on power consumption
- Solution: Deployment of QT-1411



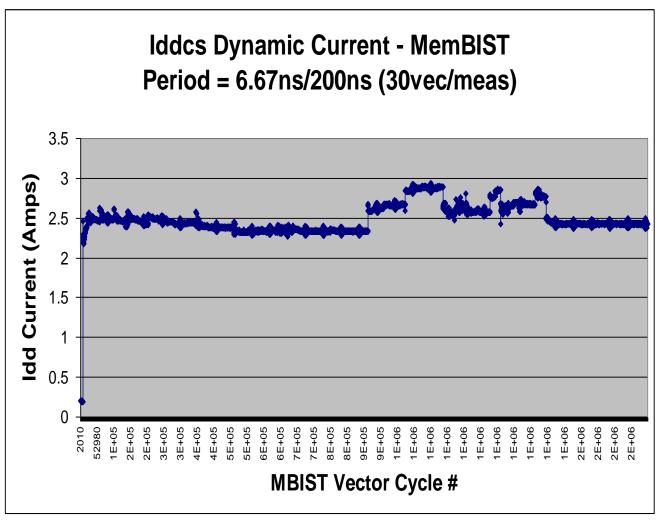
Current behavior



Initial problem observation: VDD droop

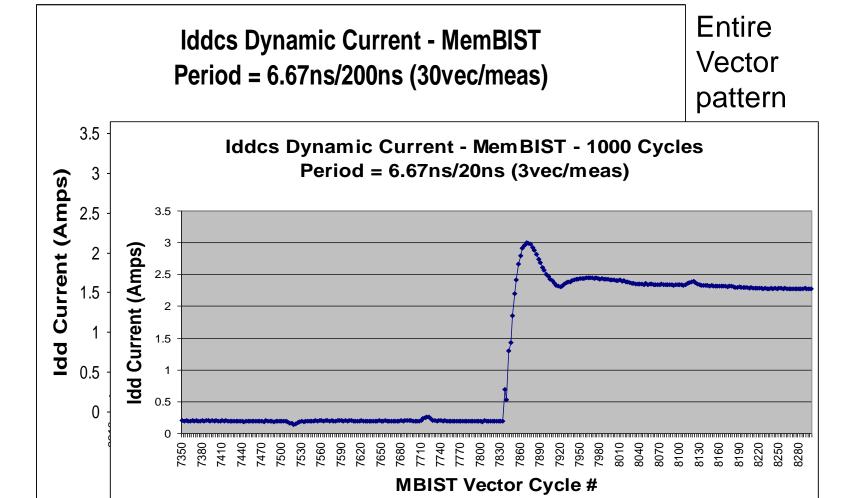






Entire Vector pattern







Benefits of good power profiling:

- Design engineering
 - → design verifies marketing requirements
 - → early and easy design tools adjustments for faster time to market

Test engineering

- → identification of current and voltage droop issues
- lower cost of test with faster test program debugging and execution

Product Engineering

better tool to monitor the silicon process and faster identifications of variances and processing speeds

Failure analysis

→ identification of IC fault locations with the comparison of the known good device current signature



Conclusions

- Q-Star's QT-1411 met LSI's dynamic signature requirements by providing
 - → fast and accurate results
 - → flexible sampling rate
 - → fast and easy implementation on the V93000
- The dynamic current signature resulted in
 - → faster time to market
 - → Improved test quality
 - → Increased device & system reliability
 - → Cost of Test savings



Other examples

Freescale:

"Making use of Q-Star Test's QD-1020 product allows us to reduce test costs whilst meeting our stringent quality demands when implementing our advanced IDDQ screening methodologies that include running hundred's of IDDQ strobe points, as well as offering us improved IDDQ data quality"

Dialog Semiconductor:

 "Combining precise current measurements and appropriate data processing ensures product reliability and eliminates the need for burn-in as reliability screen"

TSMC and IBM:

 "Precise current profiling of fuse burning current ensures reliability of reconfigured memories and avoids "walking wounded" entering the field"

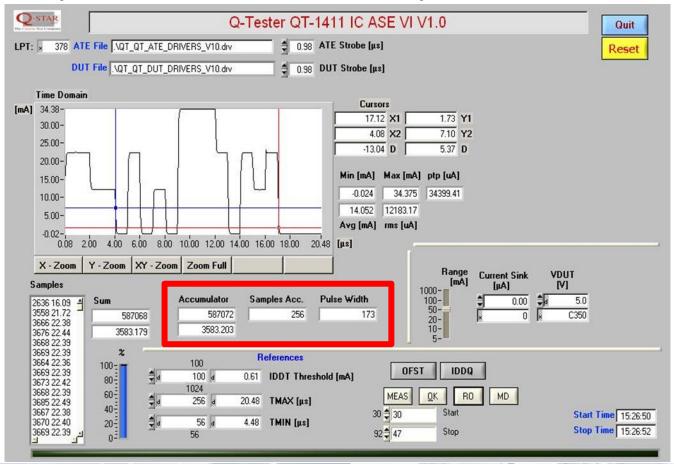
Sharp:

- "Enabled by a Q-Star IDDQ monitor, a die-to-die & test set-up independent DSM strategy based on Current Ratios was developed & successfully implemented in a production environment, yielding significant improvement of product quality and reliability".
- Reliability qualification of remote controllers



Remote controller

Battery lifetime – reliability assessment



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Conclusions

- "Current" hides/reveals reliability related info.
- Precise measurements of both Static and Dynamic current behavior unlock the secrets and support easily identification of reliability risks at device – board – system level.
- Requires use/deployment of appropriate instrumentation, eventually combined with suitable data analysis strategies.





- Slides and recording of the webinar will be available shortly via an e-mail from Ridgetop
- E-mail follow-up questions & comments to hans.manhaeve@ridgetop.eu
- Please fill out our brief feedback survey at <u>https://www.surveymonkey.com/r/R5GYLND</u>

Thanks for your time and interest!

Thank you!

Ridgetop Group, Inc.



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